

# ST485

## LOW POWER RS-485/RS-422 TRANSCEIVER

- LOW QUIESCENT CURRENT: 300µA
- DESIGNED FOR RS-485 INTERFACE APPLICATIONS
- -7V TO 12V COMMON MODE INPUT VOLTAGE RANGE
- DRIVER MAINTAINS HIGH IMPEDANCE IN 3-STATE OR WITH THE POWER OFF
- 70mV TYPICAL INPUT HYSTERESIS
- 30ns PROPAGATION DELAYS, 5ns SKEW
- OPERATE FROM A SINGLE 5V SUPPLY
- CURRENT LIMITING AND THERMAL SHUTDOWN FOR DRIVER OVERLOAD PROTECTION
- ALLOWS UP TO 64 TRANSCEIVERS ON THE BUS

### DESCRIPTION

**ORDERING CODES** 

The ST485 is al low power transceiver for RS-485 and RS-422 communication. Each part contains one driver and one receiver.

This transceiver draw  $300\mu A$  (typ.) of supply current when unloaded or fully loaded with disabled drivers.

# DIP SOP

It operates from a single 5V supply.

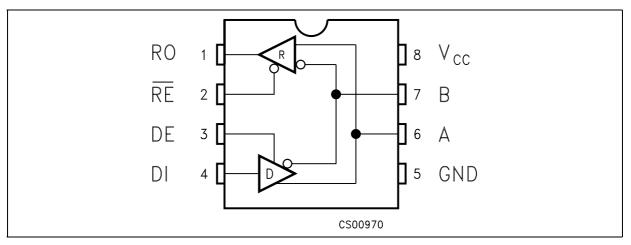
Driver is short-circuit current limited and is protected against excessive power dissipation by thermal shutdown circuitry that placed the driver outputs into a high-impedance state.

The ST485 is designed for bi-directional data communications on multipoint bus transmission line (half-duplex applciations).

The ST485 is available in three temperature range: commercial (0°C to 70°C), industrial (-40°C to 850°C) and automotive (-55°C to 125°C)

Туре	Temperature Range	Package	Comments
ST485CN	0 to 70 °C	DIP-8	50parts per tube / 40tube per box
ST485BN	-40 to 85 °C	DIP-8	50parts per tube / 40tube per box
ST485XN	-55 to 125 °C	DIP-8	50parts per tube / 40tube per box
ST485CD	0 to 70 °C	SO-8 (Tube)	100parts per tube / 20tube per box
ST485BD	-40 to 85 °C	SO-8 (Tube)	100parts per tube / 20tube per box
ST485XD	-55 to 125 °C	SO-8 (Tube)	100parts per tube / 20tube per box
ST485CDR	0 to 70 °C	SO-8 (Tape & Reel)	2500 parts per reel
ST485BDR	-40 to 85 °C	SO-8 (Tape & Reel)	2500 parts per reel
ST485XDR	-55 to 125 °C	SO-8 (Tape & Reel)	2500 parts per reel

### **PIN CONFIGURATION**



### **PIN DESCRIPTION**

PIN N°	SYMBOL	NAME AND FUNCTION
1	RO	Receiver Output
2	RE	Receiver Output Enable
3	DE	Driver Output Enable
4	DI	Driver Input
5	GND	Ground
6	A	Non-inverting Receiver Input and Non-inverting Driver Output
7	В	Inverting Receiver Input and Inverting Driver Output
8	Vcc	Supply Voltage

### TRUTH TABLE (DRIVER)

	INPUTS	OUTPUTS		
RE	DE	DI	В	Α
Х	Н	Н	L	Н
Х	Н	L	Н	L
Х	L	Х	Z	Z

X= Don't Care; Z=High Impedance

### **TRUTH TABLE (RECEIVER)**

	OUTPUT			
RE	RE DE A-B			
L	L	≥ +0.2V	Н	
L	L	≤ <b>-</b> 0.2V	L	
L	L	INPUTS OPEN	Н	
Н	L	Х	Z	

X= Don't Care; Z=High Impedance

### ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Supply Voltage	7	V
VI	Control Input Voltage (RE, DE)	-0.5 to (V <sub>CC</sub> + 0.5)	V
V <sub>DI</sub>	Driver Input Voltage (DI)	-0.5 to (V <sub>CC</sub> + 0.5)	V
V <sub>DO</sub>	Driver Output Voltage (A, B)	± 14	V
V <sub>RI</sub>	Receiver Input Voltage (A, B)	± 14	V
V <sub>RO</sub>	Receiver Output Voltage (RO)	-0.5 to (V <sub>CC</sub> + 0.5)	V

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

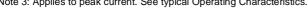
### **DC ELECTRICAL CHARACTERISTICS**

(V<sub>CC</sub> = 5V ± 5%, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise specified. Typical values are referred to T<sub>A</sub> = 25°C) (See Note 1)

				Value					
Symbol	Parameter	Test Conditions	-4	0 to 85	°C	-55 to	125 °C	Unit	
			Min.	Тур.	Max.	Min.	Max.		
V <sub>OD1</sub>	Differential Driver Output (No Load)				5		5	V	
V <sub>OD2</sub>	Differential Driver Output (With Load)		1.5		5 5	1.4	5 5	V V	
$\Delta V_{OD}$	Change in Magnitude of Driver Differential Output Voltage for Complementary Output States	$R_L = 27\Omega \text{ or } 50\Omega \text{ (See Fig. 1)}$			0.2		0.2	V	
V <sub>OC</sub>	Driver Common-Mode Output Voltage	$R_L = 27\Omega \text{ or } 50\Omega \text{ (See Fig. 1)}$			3		3	V	
$\Delta V_{OC}$	Change in Magnitude of Driver Common-Mode Output Voltage for Complementary Output States	$R_L = 27\Omega \text{ or } 50\Omega \text{ (See Fig. 1)}$	- 40	i fe	0.2		0.2	V	
$V_{H}$	Input High Voltage	RE, DE, DI	2.0			2.0		V	
V <sub>IL</sub>	Input Low Voltage	RE, DE, DI 💦 🕺 🦄			0.8		0.8	V	
I <sub>IN1</sub>	Input Current	RE, DE, DI	0		± 2		± 2	μΑ	
I <sub>IN2</sub>	Input Current (A, B)	$V_{CM} = 0V \text{ or } 5.25V V_{DE} = 0V$ $V_{IN} = 12V$ $V_{IN} = -7V$			1 -0.8		1 -0.8	mA mA	
$V_{TH}$	Receiver Differential Threshold Voltage	$V_{CM} = -7$ to 12V	-0.2		0.2	-0.2	0.2	V	
$\Delta V_{TH}$	Receiver Input Hysteresis	$V_{CM} = 0V$		70				mV	
V <sub>OH</sub>	Receiver Output High Voltage	$I_{O} = -4mA$ $V_{ID} = 200mV$	3.5			3.4		V	
V <sub>OL</sub>	Receiver Output Low Voltage	$I_{O} = 4mA$ $V_{ID} = -200mV$			0.4		0.55	V	
I <sub>OZR</sub>	3-State (High Impedance) Output Current at Receiver	$V_{O} = 0.4 \text{ to } 2.4 \text{V}$			± 1		± 1	μA	
R <sub>IN</sub>	Receiver Input Resistance	V <sub>CM</sub> = -7 to 12V	24			24		KΩ	
I <sub>CC</sub>	No Load Supply Current (Note 2)	$V_{RE} = 0V \text{ or } V_{CC}$ $V_{DE} = V_{CC}$ $V_{DE} = 0V$		400 300	900 500		900 500	μΑ μΑ	
I <sub>OSD1</sub>	Driver Short-Circuit Current, V <sub>O</sub> =High	V <sub>O</sub> = -7 to 12V (Note 3)	35		250	35	250	mA	
I <sub>OSD2</sub>	Driver Short-Circuit Current, V <sub>O</sub> =Low	V <sub>O</sub> = -7 to 12V (Note 3)	35		250	35	250	mA	
I <sub>OSR</sub>	Receiver Short-Circuit Current	$V_{O} = 0V$ to $V_{CC}$	7		95	7	95	mA	

Note 1: All currents into device pins are positive; all cuttents out of device pins are negative; all voltages are referenced to device ground unless specified.

Note 2: Supply current specification is valid for loaded transmitters when  $V_{DE} = 0V$ Note 3: Applies to peak current. See typical Operating Characteristics.





### DRIVER SWITCHING CHARACTERISTICS

 $(V_{CC} = 5V \pm 5\%, T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise specified. Typical values are referred to  $T_A = 25$ °C) (See Note 1)

			Value						
Symbol	Parameter	Test Conditions		-4	0 to 85	°C	-55 to 125 °C		Unit
				Min.	Тур.	Max.	Min.	Max.	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Input to Output	$R_{DIFF} = 54\Omega C_{L1} =$ (See Fig. 3 and 5)	- C <sub>L2</sub> = 100pF	10	30	60		70	ns
t <sub>SK</sub>	Output Skew to Output	$R_{DIFF} = 54\Omega C_{L1} =$ (See Fig. 3 and 5)	C <sub>L2</sub> = 100pF		5	10		10	ns
t <sub>TLH</sub> t <sub>THL</sub>	Rise or Fall Time	R <sub>DIFF</sub> = 54Ω 100pF	C <sub>L1</sub> = C <sub>L2</sub> =	3	15	40	3	45	ns
		(See Fig. 3 and 5)							
t <sub>PZH</sub>	Output Enable Time	C <sub>L</sub> = 100pF (See Fig. 4 and 6)	S2 = Closed		70	90		90	ns
t <sub>PZL</sub>	Output Enable Time	C <sub>L</sub> = 100pF (See Fig. 4 and 6)	S1 = Closed		70	90		90	ns
t <sub>PLZ</sub>	Output Disable Time	C <sub>L</sub> = 15pF (See Fig. 4 and 6)	S1 = Closed		70	90		90	ns
t <sub>PHZ</sub>	Output Disable Time	C <sub>L</sub> = 15pF (See Fig. 4 and 6)	S2 = Closed	2 S	70	90		90	ns

Note 1: All currents into device pins are positive; all cuttents out of device pins are negative; all voltages are referenced to device ground unless specified.

### RECEIVER SWITCHING CHARACTERISTICS

 $(V_{CC} = 5V \pm 5\%, T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise specified. Typical values are referred to  $T_A = 25^{\circ}C$ ) (See Note 1)

						Value			
Symbol	Parameter	Test Conc	Test Conditions		-40 to 85 °C			-55 to 125 °C	
				Min.	Тур.	Max.	Min.	Max.	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Input to Output	R <sub>DIFF</sub> = 54Ω 100pF (See Fig. 3 and 7)	C <sub>L1</sub> = C <sub>L2</sub> =	20	130	210		230	ns
t <sub>SKD</sub>	Differential Receiver Skew	R <sub>DIFF</sub> = 54Ω 100pF (See Fig. 3 and 7)	C <sub>L1</sub> = C <sub>L2</sub> =		13				ns
t <sub>PZH</sub>	Output Enable Time	C <sub>RL</sub> = 15pF (See Fig. 2 and 8)	S1 = Closed		20	50		56	ns
t <sub>PZL</sub>	Output Enable Time	C <sub>RL</sub> = 15pF (See Fig. 2 and 8)	S2 = Closed		20	50		56	ns
t <sub>PLZ</sub>	Output Disable Time	C <sub>RL</sub> = 15pF (See Fig. 2 and 8)	S1 = Closed		20	50		56	ns
t <sub>PHZ</sub>	Output Disable Time	C <sub>RL</sub> = 15pF (See Fig. 2 and 8)	S2 = Closed		20	50		56	ns
f <sub>MAX</sub>	Maximum Data Rate			2.5			2.5		Mbps

Note 1: All currents into device pins are positive; all cuttents out of device pins are negative; all voltages are referenced to device ground unless specified.

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### TEST CIRCUITS AND TYPICAL CHARACTERISTICS

### Figure 1 : Driver DC Test Load

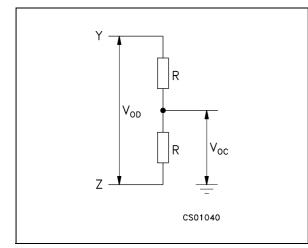
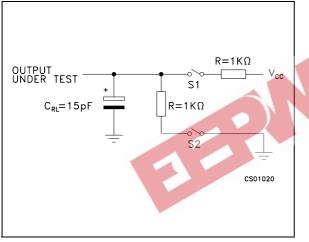
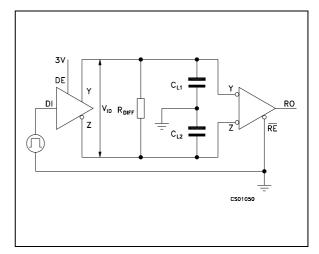


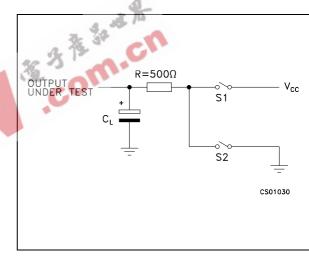
Figure 2 : Receiver Timing Test Load



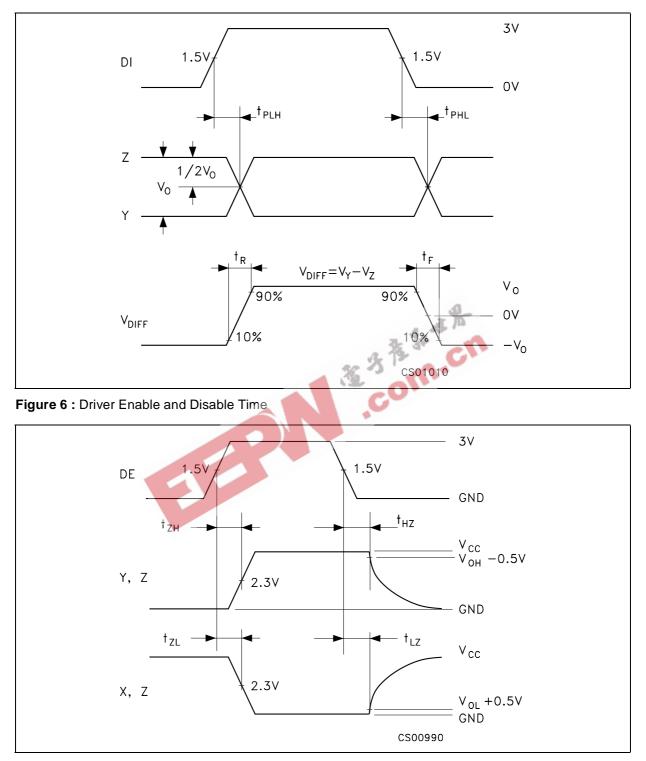
### Figure 3 : Drive/Receiver Timing Test Circuit





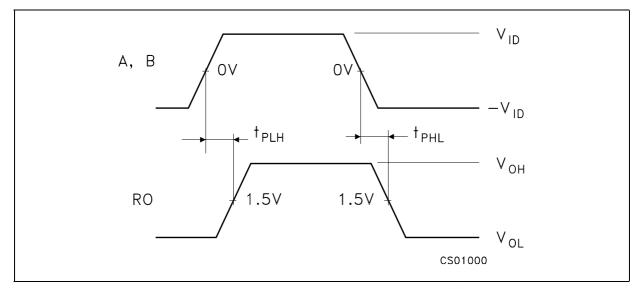






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Figure 7 : Receiver Propagation Delay





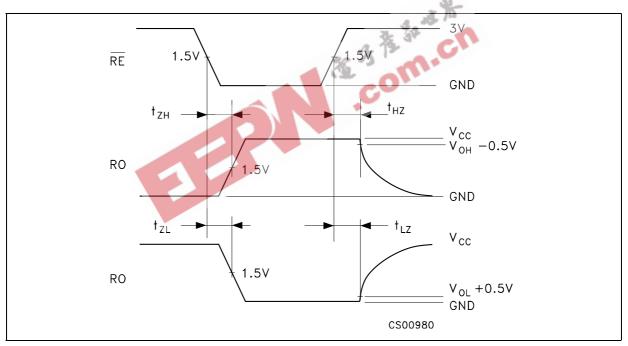
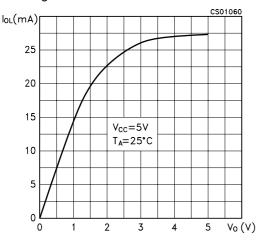


Figure 9 : Receiver Output Current vs Output Low Voltage



**Figure 10 :** Receiver Output Current vs Output High Voltage

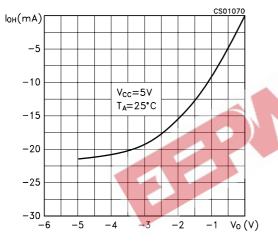


Figure 11 : Driver Output Current vs Output Low Voltage

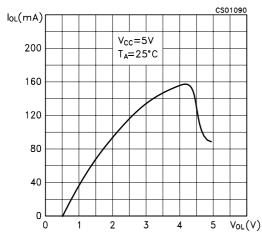


Figure 12 : Driver Output Current vs Output High Voltage

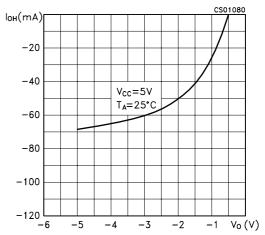
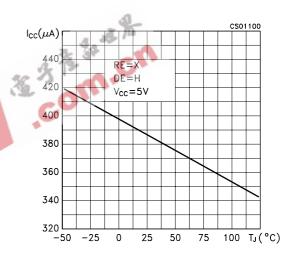
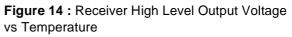
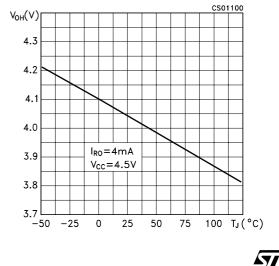


Figure 13 : Supply Current vs Temperature







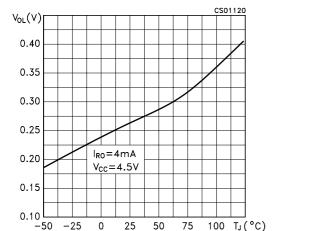
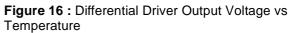
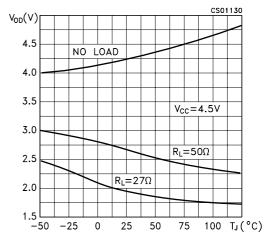


Figure 15 : Receiver Low Level Output Voltage vs Temperature







	Plastic DIP-8 MECHANICAL DATA									
DIM.		mm.			inch					
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.				
А		3.3			0.130					
a1	0.7			0.028						
В	1.39		1.65	0.055		0.065				
B1	0.91		1.04	0.036		0.041				
b		0.5			0.020					
b1	0.38		0.5	0.015		0.020				
D			9.8			0.386				
E		8.8			0.346					
е		2.54			0.100					
e3		7.62			0.300					
e4		7.62			0.300					
F			7.1	34 St	-	0.280				
I			4.8	372		0.189				
L		3.3	132	on	0.130					
Z	0.44		1.6	0.017		0.063				

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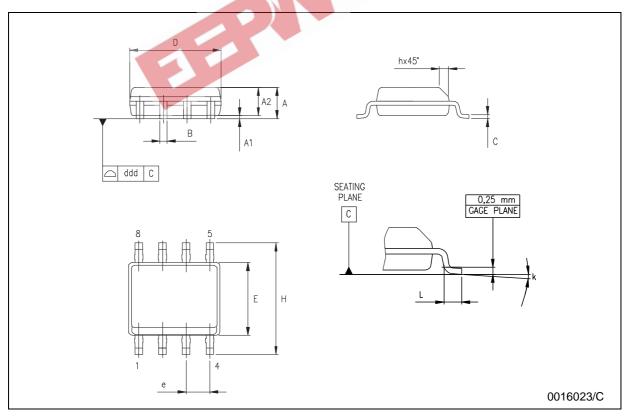


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### e4 1 **... b1** Ε b e e3 Ζ Ζ D 5 8 11 4 P001F

DIM.		mm.			inch	
	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.
А	1.35		1.75	0.053		0.069
A1	0.10		0.25	0.04		0.010
A2	1.10		1.65	0.043		0.065
В	0.33		0.51	0.013		0.020
С	0.19		0.25	0.007		0.010
D	4.80		5.00	0.189		0.197
E	3.80		4.00	0.150		0.157
е		1.27			0.050	
н	5.80		6.20	0.228	3	0.244
h	0.25		0.50	0.010	D.	0.020
L	0.40		1.27	0.016		0.050
k			8°	(max.)		•



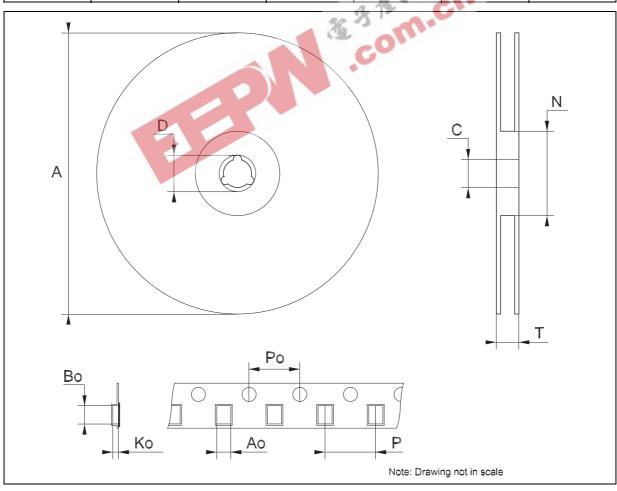


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	Tape & Reel SO-8 MECHANICAL DATA									
DIM	mm. inch									
DIM.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.				
A			330			12.992				
С	12.8		13.2	0.504		0.519				
D	20.2			0.795						
Ν	60			2.362						
Т			22.4			0.882				
Ao	8.1		8.5	0.319		0.335				
Во	5.5		5.9	0.216		0.232				
Ko	2.1		2.3	0.082		0.090				
Po	3.9		4.1	0.153	-	0.161				
Р	7.9		8.1	0.311	~	0.319				



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